TOSHIBA Field Effect Transistor Silicon P Channel MOS Type ( $L^2$ - $\pi$ -MOSV)

# **2SJ465**

# DC-DC Converter, Relay Drive and Motor Drive Applications

• 2.5-V gate drive

• Low drain-source ON-resistance :  $RDS(ON) = 0.54 \Omega \text{ (typ.)}$ 

• High forward transfer admittance :  $|Y_{fs}| = 1.7 \text{ S (typ.)}$ 

• Low leakage current :  $IDSS = -100 \mu A \text{ (max) (VDS} = -16 \text{ V)}$ 

• Enhancement mode :  $V_{th} = -0.5$  to -1.1 V

 $(V_{DS} = -10 \text{ V}, I_{D} = -200 \text{ }\mu\text{A})$ 

### **Absolute Maximum Ratings (Ta = 25°C)**

Characteris	etics	Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	-16	$\bigvee$
Drain-gate voltage (Ro	<sub>SS</sub> = 20 kΩ)	$V_{DGR}$	-16	$\rightarrow$
Gate-source voltage		$V_{GSS}$	£8	∨
Drain current	DC (Note 1)	I <sub>D</sub>	-2	Α
	Pulse (Note 1)	I <sub>DP</sub>	-6	A .
Drain power dissipation	1	PD	0.5	/ (w
Drain power dissipation	(Note 2)	PD	1.5	W
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature range		T <sub>stg</sub>	−55 to 150	∕ °C

Unit: mm

4,6MAX.
1,7MAX.
0,4±0.05

0,45-0.05

0,4-0.05

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Weight: 0.05 g (typ.)

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Mounted on a ceramic substrate (25.4 mm × 25.4 mm × 0.8 mm)

Note 3: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	250	°C/W

This transistor is an electrostatic-sensitive device.

Please handle with caution.

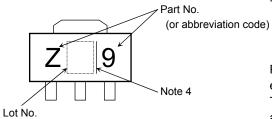
### **Electrical Characteristics (Ta = 25°C)**

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I <sub>GSS</sub>	V <sub>GS</sub> = ±6.5 V, V <sub>DS</sub> = 0 V	_	_	±10	μΑ
Drain cut-off cu	rrent	I <sub>DSS</sub>	V <sub>DS</sub> = -16 V, V <sub>GS</sub> = 0 V	_	_	-100	μΑ
Drain-source br voltage	eakdown	V (BR) DSS	$I_D = -10$ mA, $V_{GS} = 0$ V	-16	_	ı	V
Gate threshold v	oltage/	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_D = -200 \mu\text{A}$	(+0.5	7	-1.1	V
Drain-source ON-resistance		R <sub>DS (ON)</sub>	$V_{GS} = -2.5 \text{ V}, I_D = -0.5 \text{ A}$		0.82	1.0	Ω
			$V_{GS} = -4 \text{ V}, I_D = -1 \text{ A}$	$\langle \hat{A} \rangle$	0.54	0.71	22
Forward transfer	r admittance	Y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 A	0.8	1.7	_	S
Input capacitance		C <sub>iss</sub>		· —	270	1	
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	25	_	pF
Output capacitance		Coss	2( >>	_	115	//	
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> OV ] [ P - 1A OUT	-	200	> —	
	Turn-on time	t <sub>on</sub>	$-5V$ $R_{L}=8\Omega$		250	_	
	Fall time	t <sub>f</sub>	Van = 8W	2	200	_	ns
	Turn-off time	t <sub>off</sub>	$V_{DD} = -8V$ $Duty \le 1\%, t_{\mathbf{w}} = 10\mu s$	) _	500	_	
Total gate charge (Gate-source plus gate-drain)		Q <sub>g</sub>		_	5	_	
Gate-source charge		Qgs	$V_{DD} \approx -16 \text{ V}, V_{GS} = -5 \text{ V}, I_D = -2 \text{ A}$		3.2		nC
Gate-drain ("miller") charge		Qgd		_	1.8	_	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	IDR	_	ı	ı	-2	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	-	-	-6	Α
Forward voltage (diode)	VDSF	$I_{DR} = -2 \text{ A}, V_{GS} = 0 \text{ V}$	1	1	1.7	V
Reverse recovery time	t <sub>rr</sub>	<sub>IDR</sub> = −2 A, V <sub>GS</sub> = 0 V		130	_	ns
Reverse recovery charge	Qrr	dl <sub>DR</sub> / dt = 50 A / μs	_	0.13	_	μC

Marking

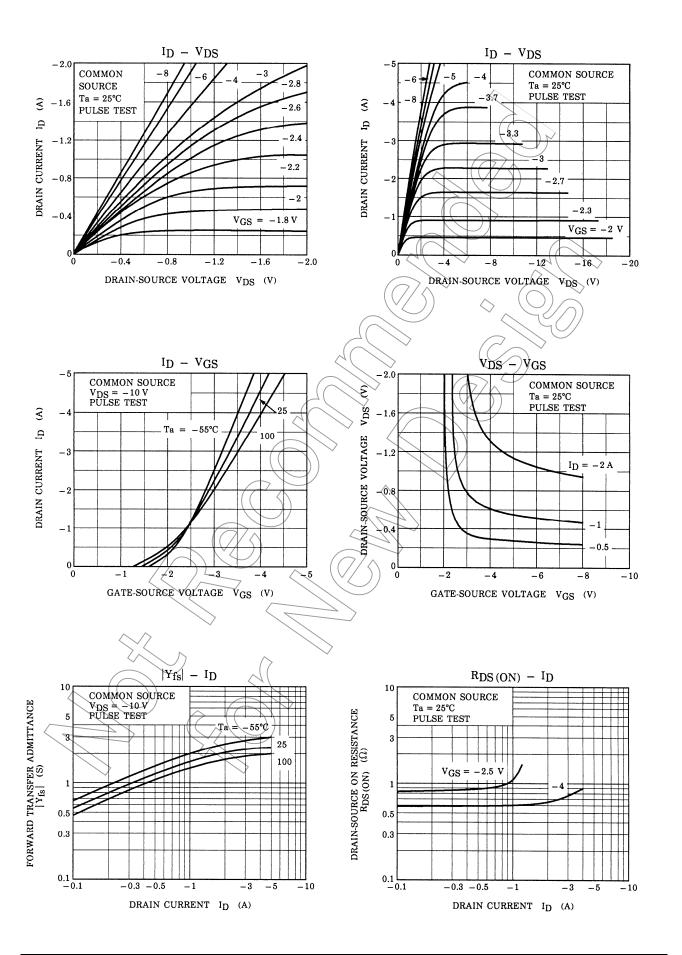


Note 4: A line to the right of a Lot No. identifies the indication of product Labels.

Without a line: [[Pb]]/INCLUDES > MCV

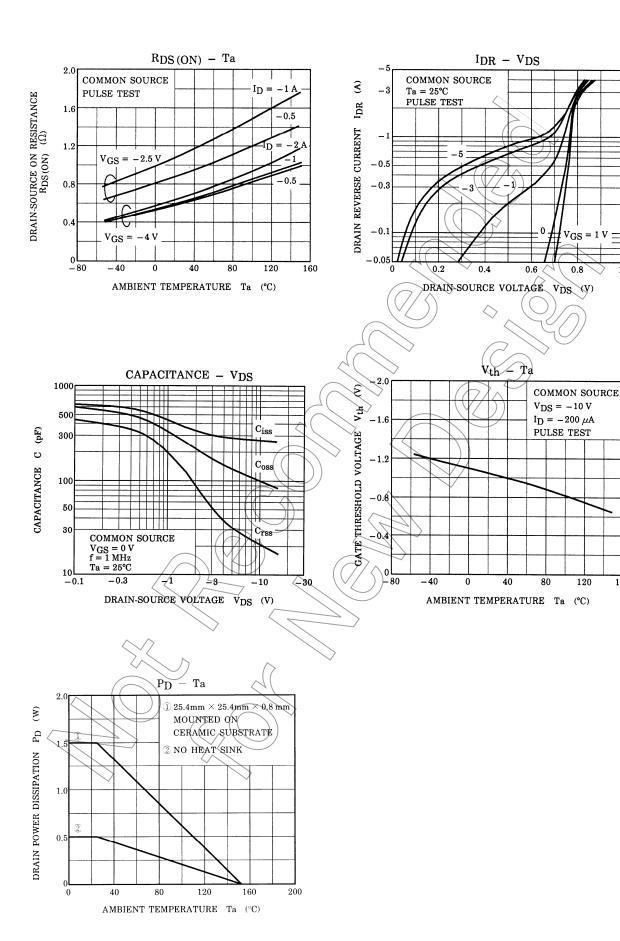
With a line: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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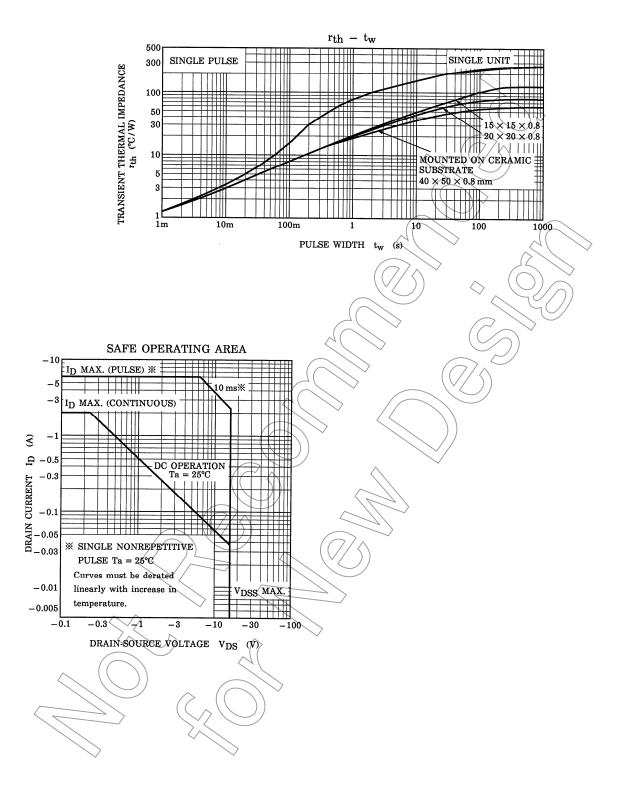


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